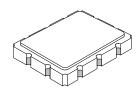
# SF1133A 246 MHz SAW Filter



## **PRELIMINARY**

- Designed For GSM BTS Receiver IF
- Compatible with National Semiconductor Chip Set
- Very Flexible Impedance Matching
- Unbalanced or Balanced Input or Output



#### $\int \int_{\mathbb{R}^n}$

Characteristi	ic	Sym	Min	Тур	Max	Units	Notes
Nominal Center Frequency				246.000		MHz	1
Passband	Insertion Loss at fc	IL			7.0	dB	
	1 dB Passband	BW <sub>1</sub>	±100			kHz	1, 2
	Amplitude Ripple over fc ±100 kHz				1.0	dB <sub>P-P</sub>	
	Group Delay Variation over fc ±100 kHz	GDV			500	ns <sub>P-P</sub>	
Rejection	fc-800 to fc-600 and fc+600 to fc+800 kHz		20			dB	1, 2, 3
	fc-30 MHz to fc-800 kHz		30				
	fc+800 kHz to fc+17 MHz		30				
	fc-80 MHz to fc-30 MHz		35				
	fc+17 MHz to fc+80 MHz		35				
Operating Temperature Range		T <sub>A</sub>	-35		+85	°C	1

Impedance Matching to 50 $\Omega$ unbalanced Impedance Matching to 200 $\Omega$ balanced	External L-C External L-C			
Case Style	SM9171-10 9.1 x 7.1 mm Nominal Footprint			
Lid Symbolization (YY = year, WW = Week)	RFM SF1133A YYWW			

# **Absolute Maximum Ratings**

Rating	Value	Units
Maximum Incident Power in Passband	+15	dBm
Max. DC voltage between any 2 terminals	30	VDC
Storage Temperature Range	-40 to +85	°C
Max Soldering Profile	265°C for	10 s

# **Electrical Connections**

Connection	Terminals				
Port 1 Hot	10				
Port 1 Return	1				
Port 2 Hot	5				
Port 2 Return	6				
Case Ground	All Others				

#### Notes:

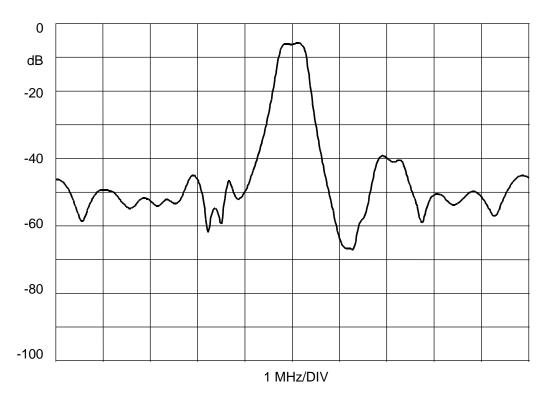
- 1. Unless noted otherwise, all specifications apply *over the operating temperature range* with filter soldered to the specified demonstration board with impedance matching to 50 Ω and measured with 50 Ω network analyzer.
- 2. Unless noted otherwise, all frequency specifications are referenced to the nominal center frequency, fc.
- 3. Rejection is measured as attenuation below the minimum IL point in the passband. Rejection in final user application is dependent on PCB layout and external impedance matching design. See Application Note No. 42 for details.
- 4. "LRIP" or "L" after the part number indicates "low rate initial production" and "ENG" or "E" indicates "engineering prototypes."
- 5. The design, manufacturing process, and specifications of this filter are subject to change.
- 6. Either Port 1 or Port 2 may be used for either input or output in the design. However, impedances and impedance matching may vary between Port 1 and Port 2, so that the filter must always be installed in one direction per the circuit design.
- 7. US and international patents may apply.
- 8. RFM, stylized RFM logo, and RF Monolithics, Inc. are registered trademarks of RF Monolithics, Inc.
- 9. ©Copyright 1999, RF Monolithics Inc.
- 10. Electrostatic Sensitive Device. Observe precautions for handling.

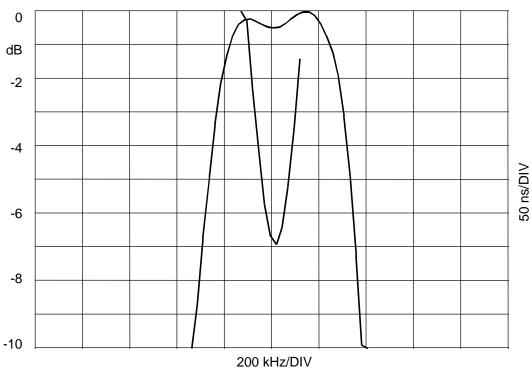


**RF Monolithics, Inc.** 4347 Sigma Road Dallas, Texas 75244 USA Phone: +1(972)233-2903 Fax: +1(972)387-8148 e-mail: <u>info@rfm.com</u> Home page: www.rfm.com

**European Sales Office** 44 1963 251383 44 1963 251510

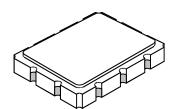








# 10-Terminal Ceramic Surface-Mount Case 9.1 x 7.1 mm Nominal Footprint

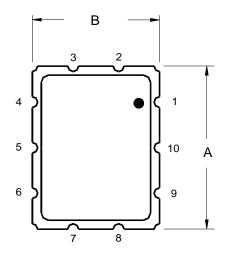


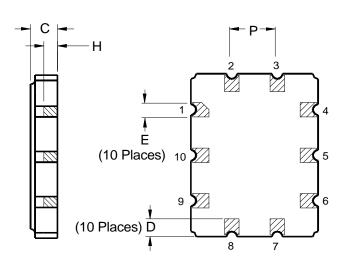
#### **Case Dimensions**

Dimension	mm			Inches			
Dilliension	Min	Nom	Max	Min	Nom	Max	
Α	8.86	9.09	9.40	0.349	0.358	0.370	
В	6.88	7.11	7.40	0.271	0.280	0.291	
С		1.91	2.00		0.075	0.079	
D		0.99			0.039		
E		0.79			0.031		
Н		1.0			0.039		
Р		2.54			0.100		

### **Electrical Connections**

	Connection	Terminals		
Port 1	Input or Return	6		
	Return or Input	5		
Port 2	Output or Return	1		
	Return or Output	10		
	Ground	All others		
Single Ended Operation		Return is ground		
Differential Operation		Return is hot		





RF Monolithics, Inc. Phone: (972) 233-2903 Fax: (972) 387-8148 RFM Europe Phone: 44 1963 251383 Fax: 44 1963 251510 ©1999 by RF Monolithics, Inc. The stylized RFM logo and RFM are registered trademarks of RF Monolithics, Inc.